To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

Phase-out/Discontinued

μPA1811

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μPA1811 is a switching device which can be driven directly by a 2.5-V power source.

The μPA1811 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

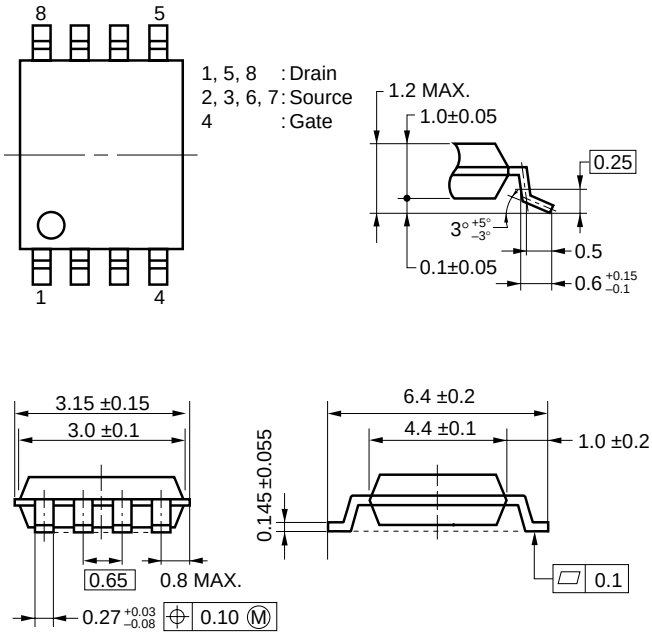
FEATURES

- Can be driven by a 2.5- V power source
- Low on-state resistance
  $R_{DS(on)1}$ = 75 mΩ MAX. (V_{GS} = –4.5 V, I_D = –2.0 A)
  $R_{DS(on)2}$ = 80 mΩ MAX. (V_{GS} = –4.0 V, I_D = –2.0 A)
  $R_{DS(on)3}$ = 120 mΩ MAX. (V_{GS} = –2.5 V, I_D = –2.0 A)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1811GR-9JG	Power TSSOP8

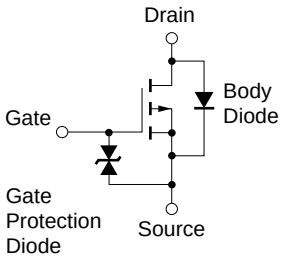
PACKAGE DRAWING (Unit : mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

	Drain to Source Voltage	V_{DSS}	–20	V
★	Gate to Source Voltage	V_{GSS}	–12/+6	V
	Drain Current (DC)	$I_{D(DC)}$	±4.0	A
	Drain Current (pulse) Note1	$I_{D(pulse)}$	±16	A
	Total Power Dissipation Note2	P_T	2.0	W
	Channel Temperature	T_{ch}	150	°C
	Storage Temperature	T_{stg}	–55 to +150	°C

EQUIVALENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1 %

2. Mounted on ceramic substrate of 5000 mm^2 x 1.1 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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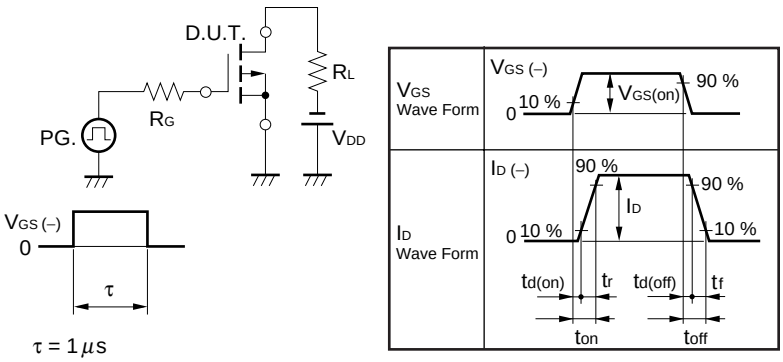
Date Published January 2000 NS CP(K)
Printed in Japan

The mark ★ shows major revised points.

ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

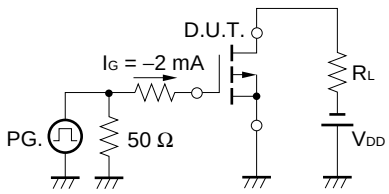
	CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = –20 V, V_{GS} = 0 V			–10	μA
	Gate Leakage Current	I_{GSS}	V_{GS} = ±12 V, V_{DS} = 0 V			±10	μA
★	Gate Cut-off Voltage	$V_{GS(off)}$	V_{DS} = –10 V, I_D = –1 mA	–0.5	–0.9	–1.5	V
★	Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = –10 V, I_D = –2.0 A	2.5	6.8		S
	Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = –4.5 V, I_D = –2.0 A		42	75	mΩ
		$R_{DS(on)2}$	V_{GS} = –4.0 V, I_D = –2.0 A		46	80	mΩ
		$R_{DS(on)3}$	V_{GS} = –2.5 V, I_D = –2.0 A		73	120	mΩ
	Input Capacitance	C_{iss}	V_{DS} = –10 V		1160		pF
	Output Capacitance	C_{oss}	V_{GS} = 0 V		680		pF
	Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		210		pF
	Turn-on Delay Time	$t_{d(on)}$	V_{DD} = –10 V		40		ns
	Rise Time	t_r	I_D = –2.0 A		100		ns
	Turn-off Delay Time	$t_{d(off)}$	$V_{GS(on)}$ = –4.0 V		90		ns
	Fall Time	t_f	R_G = 5 Ω		60		ns
	Total Gate Charge	Q_G	V_{DD} = –10 V		36		nC
	Gate to Source Charge	Q_{GS}	I_D = –4.0 A		5		nC
	Gate to Drain Charge	Q_{GD}	V_{GS} = –4.0 V		16		nC
	Diode Forward Voltage	$V_{F(S-D)}$	I_F = 4.0 A, V_{GS} = 0 V		0.74		V
	Reverse Recovery Time	t_{rr}	I_F = 4.0 A, V_{GS} = 0 V		77		ns
	Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μS		69		nC

TEST CIRCUIT 1 SWITCHING TIME



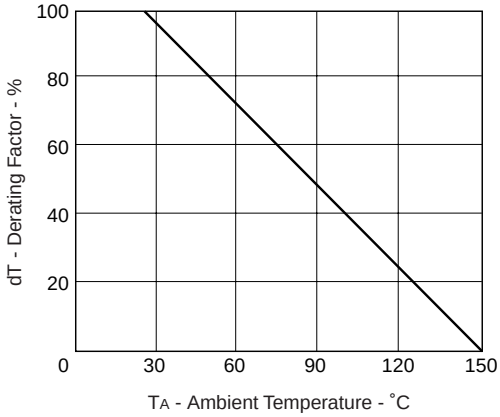
τ = 1 μs
Duty Cycle ≤ 1 %

TEST CIRCUIT 2 GATE CHARGE

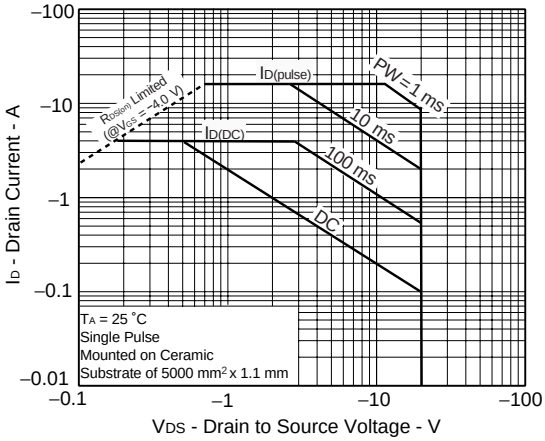


★ TYPICAL CHARACTERISTICS (T_A = 25 °C)

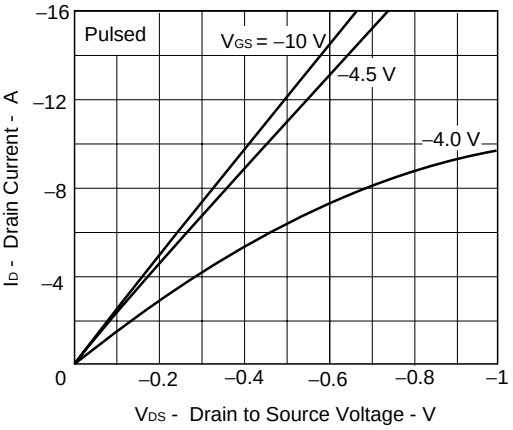
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



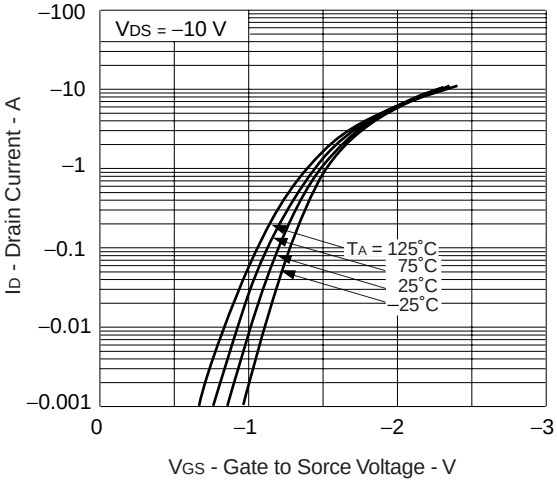
FORWARD BIAS SAFE OPERATING AREA



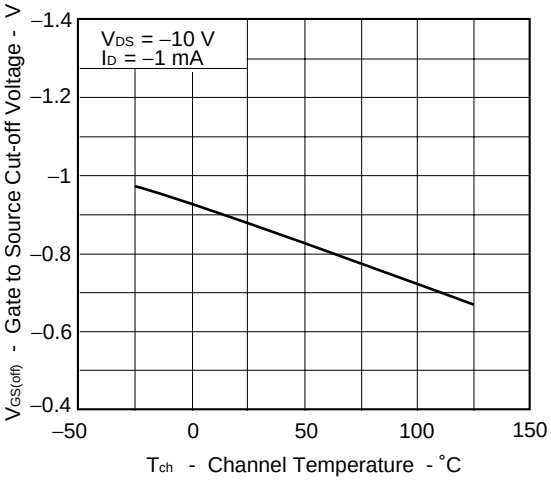
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



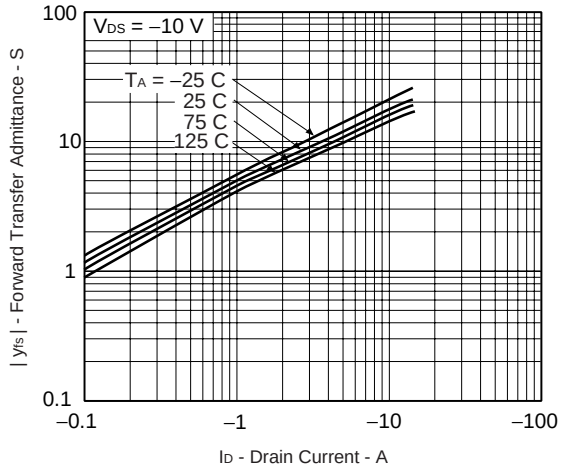
TRANSFER CHARACTERISTICS



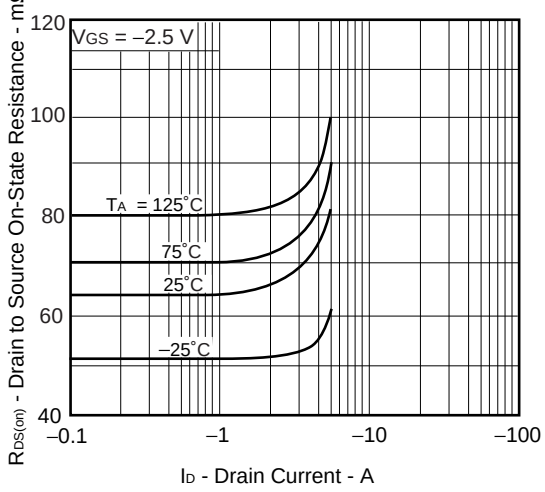
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



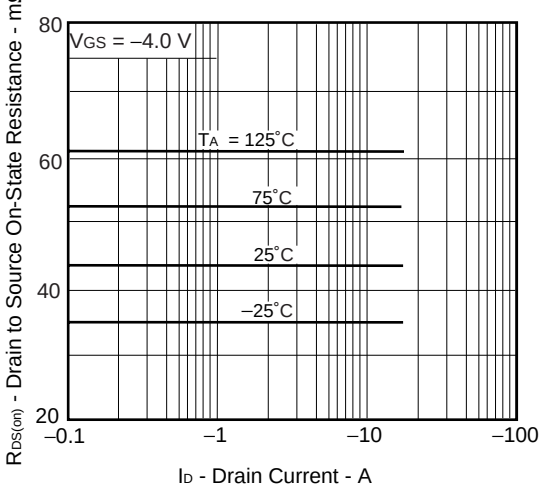
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



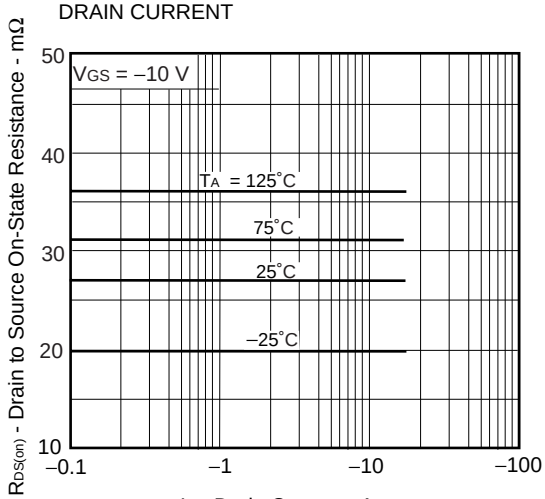
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



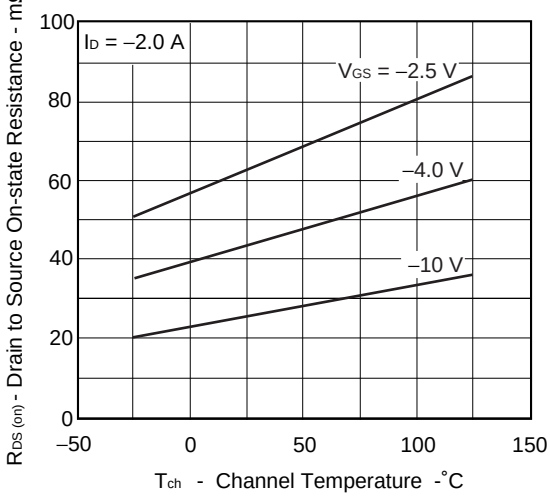
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



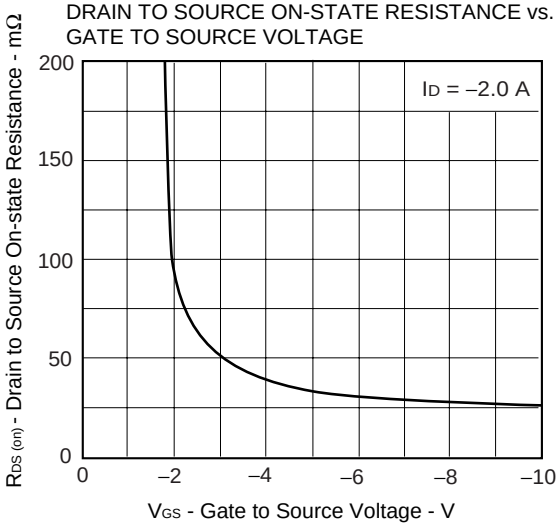
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



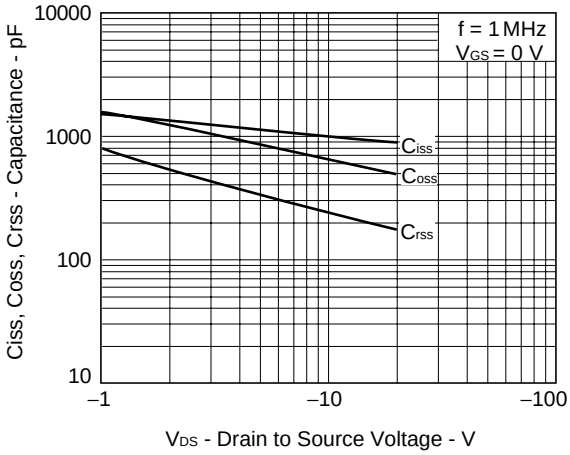
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



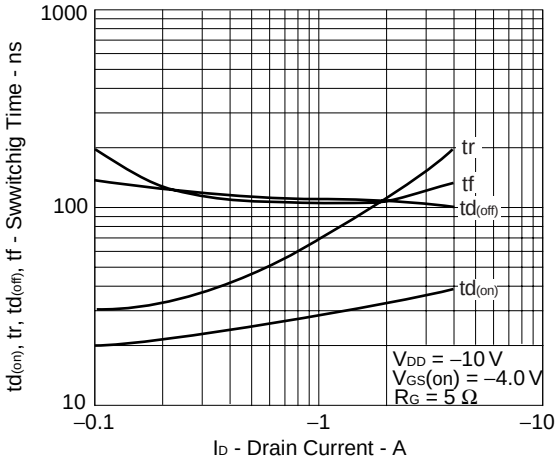
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



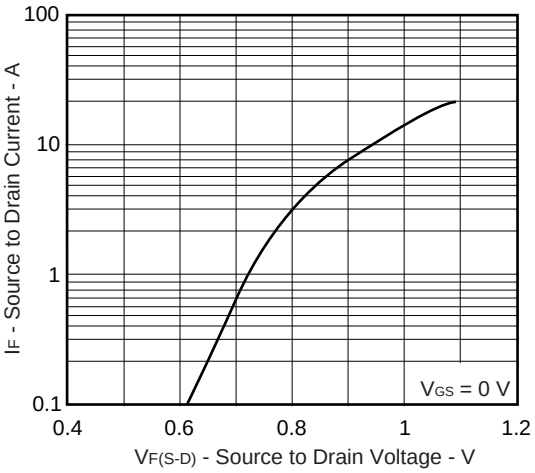
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



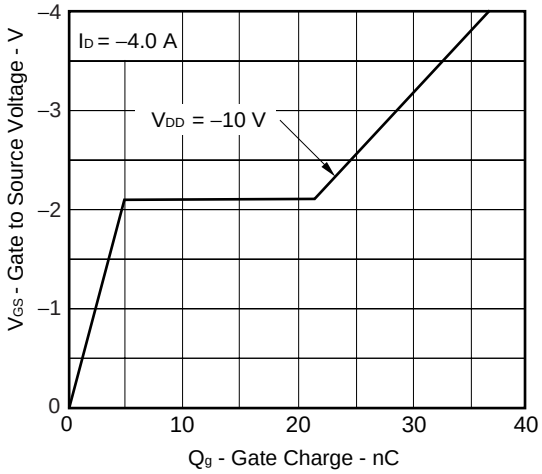
SWITCHING CHARACTERISTICS



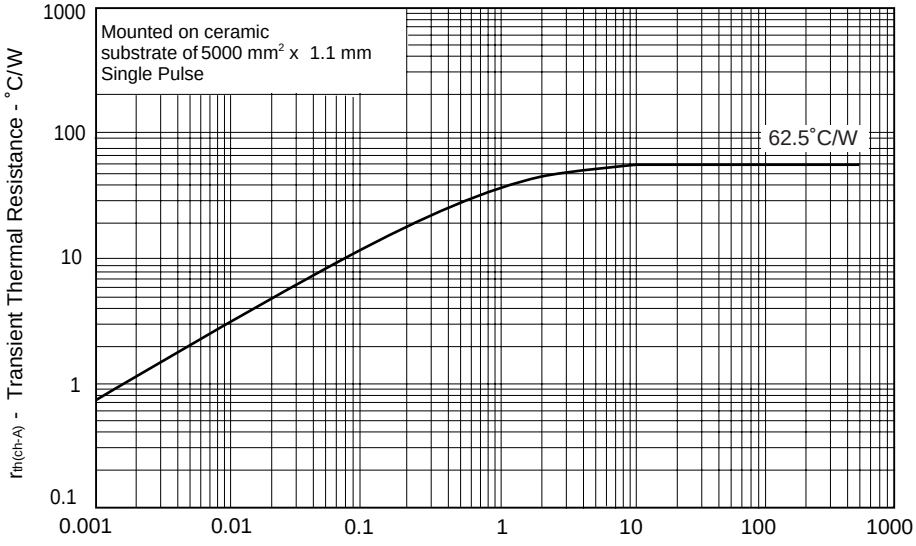
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



DYNAMIC INPUT CHARACTERISTICS



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



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